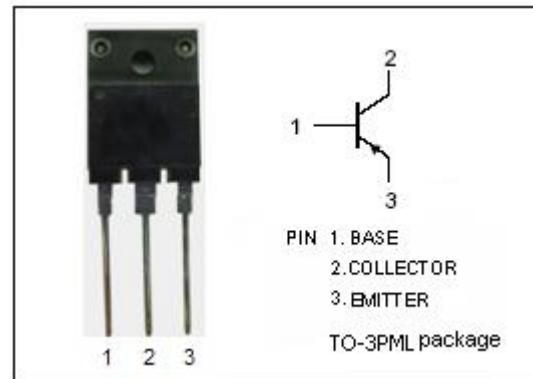


## SPTECH Silicon PNP Power Transistor

2SB778

**DESCRIPTION**

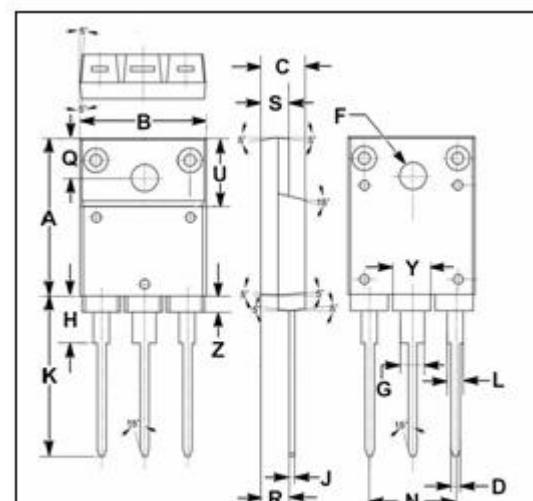
- Low Collector Saturation Voltage  
 $V_{CE(sat)} = -0.5(V)(Max) @ I_C = -5A$
- Good Linearity of  $h_{FE}$

**APPLICATIONS**

- Designed for chopper regulator, switch and general purpose applications

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-70	V
$V_{CEO}$	Collector-Emitter Voltage	-120	V
$V_{EBO}$	Emitter-Base Voltage	-6	V
$I_C$	Collector Current-Continuous	-10	A
$I_{CM}$	Collector Current-Peak	-20	A
$I_B$	Base Current-Continuous	-4	A
$P_c$	Collector Power Dissipation @ $T_c=25^\circ C$	80	W
$T_J$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature Range	-55~150	°C



DIM	mm	
	MIN	MAX
A	19.90	20.10
B	15.75	16.10
C	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
H	5.90	6.10
J	0.595	0.70
K	21.10	22.50
L	1.90	2.25
N	10.80	11.00
O	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Y	4.20	4.90
Z	1.90	2.10

# SPTECH Product Specification

## SPTECH Silicon PNP Power Transistor

**2SB778**

### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -25mA ; I <sub>B</sub> = 0	-50			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -5A; I <sub>B</sub> = -80mA			-0.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -5A; I <sub>B</sub> = -80mA			-1.2	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -70V ; I <sub>E</sub> = 0			-10	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -6V; I <sub>C</sub> = 0			-10	μ A
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -5A ; V <sub>CE</sub> = -1V	50			
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = -10V;f= 1.0MHz		400		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>E</sub> = 1A ; V <sub>CE</sub> = -12V		25		MHz

### Switching Times

t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = -5A , R <sub>L</sub> = 4 Ω , I <sub>B1</sub> = -I <sub>B2</sub> = -80mA,V <sub>CC</sub> = -20V		0.5		μ s
t <sub>stg</sub>	Storage Time			0.6		μ s
t <sub>f</sub>	Fall Time			0.3		μ s

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